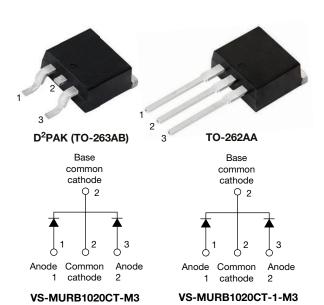
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## Ultrafast Rectifier, 2 x 5 A FRED Pt®

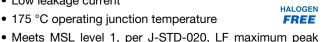


PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub>	2 x 5 A						
$V_{R}$	200 V						
V <sub>F</sub> at I <sub>F</sub>	0.87 V						
t <sub>rr</sub>	25 ns						
T <sub>J</sub> max.	175 °C						
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA						
Circuit configuration	Common cathode						

#### **FEATURES**

of 245 °C

- · Ultrafast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature



• Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

MUR.. series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Peak repetitive reverse voltage		$V_{RRM}$		200	V			
Average rectified forward current	per leg	-		5				
Average rectilled forward current	total device	I <sub>F(AV)</sub>	Rated V <sub>R</sub> , T <sub>C</sub> = 149 °C	10	٨			
Non-repetitive peak surge current p	er leg	I <sub>FSM</sub>		50	Α			
Peak repetitive forward current per	leg	I <sub>FM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 149 °C	10				
Operating junction and storage tem	peratures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	200	-	-			
		I <sub>F</sub> = 5 A, T <sub>J</sub> = 25 °C	-	0.99	1.08	] ,,		
Forward voltage	V	I <sub>F</sub> = 5 A, T <sub>J</sub> = 125 °C	-	0.87	0.99	V		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 A, T <sub>J</sub> = 25 °C	-	1.12	1.25			
		I <sub>F</sub> = 10 A, T <sub>J</sub> = 125 °C	-	1.02	1.20			
Develope legisere eviment		V <sub>R</sub> = V <sub>R</sub> rated	-	-	10			
Reverse leakage current	I <sub>R</sub>	$T_J = 150 ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	-	250	μA		
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	8	-	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH		

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			MAX.	UNITS		
		$I_F = 1.0 \text{ A}, dI_F/dt = 5$	0 A/μs, V <sub>R</sub> = 30 V	-	-	35			
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>REC</sub> = 0.25 V		-	-	25			
		T <sub>J</sub> = 25 °C		-	24	-	ns		
		T <sub>J</sub> = 125 °C		-	35	-			
Dools was as some as sweet		T <sub>J</sub> = 25 °C	$I_F = 5 A$	-	3.3	-	^		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 160 V	-	5.0	-	Α		
Develope vegetiem, charge	0	T <sub>J</sub> = 25 °C	7 VH - 100 V	-	33	-	<b>"</b> C		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	76	nC -	IIC		

THERMAL - MECHANIC	CAL SPEC	IFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C	
Thermal resistance, junction to case per leg	$R_{thJC}$		-	-	5		
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>		-	-	50	°C/W	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-		
\\\ai~b+			-	2.0	-	g	
Weight			-	0.07	-	OZ.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Madiandaia		Case style D <sup>2</sup> PAK (TO-263AB)		MURB	1020CT		
Marking device		Case style TO-262		MURB1020CT-1			

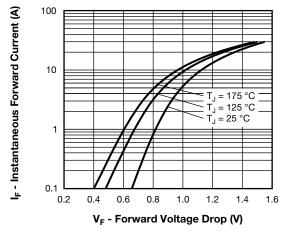


Fig. 1 - Typical Forward Voltage Drop Characteristics

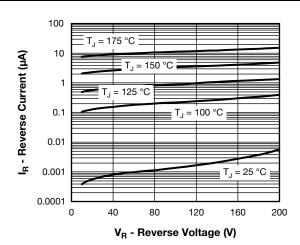


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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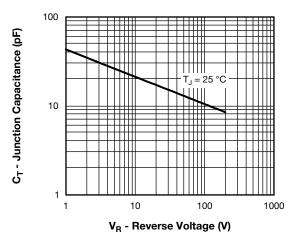


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

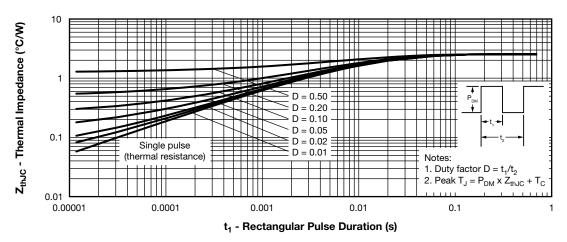


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

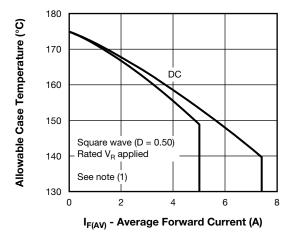


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

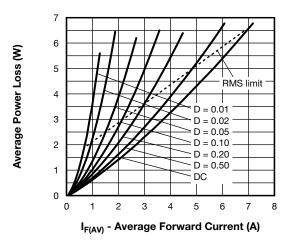


Fig. 6 - Forward Power Loss Characteristics

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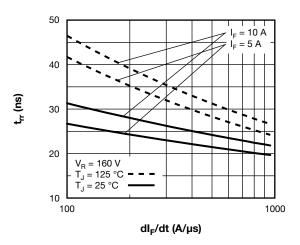


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

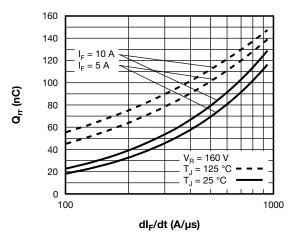
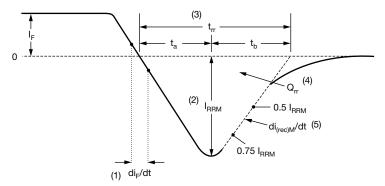


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = rated V<sub>R</sub>



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{\text{RRM}}$  peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_{rr}$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

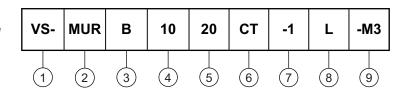
(5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 9 - Reverse Recovery Waveform and Definitions

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### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Ultrafast MUR series

 $= D^2PAK (TO-263AB) / TO-262AA$ 

4 - Current rating (10 = 10 A)

**5** - Voltage rating (20 = 200 V)

6 - CT = center tap (dual)

7 - • None = D<sup>2</sup>PAK (TO-263AB)

• -1 = TO-262AA

8 - • None = tube (50 pieces)

• L = tape and reel (left oriented, for D<sup>2</sup>PAK (TO-263AB) package)

• R = tape and reel (right oriented, for D<sup>2</sup>PAK (TO-263AB) package)

9 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Exar	ORDERING INFORMATION (Example)							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-MURB1020CTL-M3	800	13" diameter plastic tape and reel						
VS-MURB1020CT-M3	50	Antistatic plastic tubes						
VS-MURB1020CTR-M3	800	13" diameter plastic tape and reel						
VS-MURB1020CT-1-M3	50	Antistatic plastic tubes						

	LINKS TO RELATED DOCUMENTS									
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164								
Differsions	TO-262AA	www.vishay.com/doc?96165								
Dort marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444								
Part marking information -	TO-262AA	www.vishay.com/doc?95443								
Packaging information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96424								



### Vishay Semiconductors

### D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	HES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

Revision: 13-Jul-17 Document Number: 96164

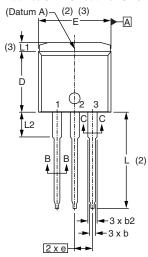


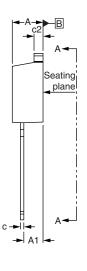
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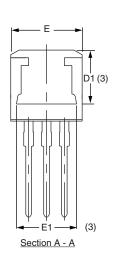
### **TO-262AA**

### **DIMENSIONS** in millimeters and inches

#### Modified JEDEC® outline TO-262







**⊕** 0.010 **M** A**M** B

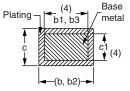
#### Lead assignments



**Diodes** 1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

CVMDOL	MILLIM	IETERS	INC	INCHES			
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
Е	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54	BSC	0.10	0 BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.56	3.71	0.140	0.146			

#### **Notes**

(4) Dimension b1 and c1 apply to base metal only

Controlling dimension: inches

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)



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